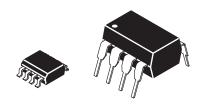
## TEXAS INSTRUMENTS



SLLS500A - MAY 2001 - REVISED MARCH 2005

## **DIFFERENTIAL BUS TRANSCEIVER**

## FEATURES

- One-Fourth Unit Load Allows up to 128 Devices on a Bus
- ESD Protection for Bus Terminals:
  - ±15-kV Human Body Model
  - ±8-kV IEC61000-4-2, Contact Discharge
  - ±15-kV IEC61000-4-2, Air-Gap Discharge
- Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-485-A and ISO 8482: 1987(E)
- Controlled Driver Output-Voltage Slew Rates Allow Longer Cable Stub Lengths
- Designed for Signaling Rates<sup>†</sup> Up to 250-kbps
- Low Disabled Supply Current . . . 250 μA Max
- Thermal Shutdown Protection
- Open-Circuit Fail-Safe Receiver Design
- Receiver Input Hysteresis . . . 70 mV Typ
- Glitch-Free Power-Up and Power-Down Protection

## APPLICATIONS

- Utility Meters
- Industrial Process Control
- Building Automation

## DESCRIPTION

The SN65LBC182 and SN75LBC182 are differential data line transceivers with a high level of ESD protection in the trade-standard footprint of the SN75176. They are designed for balanced transmission lines and meet ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC182 and SN75LBC182 combine a 3-state, differential line driver and differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected together to function as a direction control.

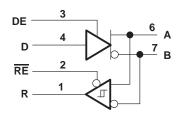
The driver outputs and the receiver inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus. This port operates over a wide range of common-mode voltage, making the device suitable for party-line applications. The device also includes additional features for party-line data buses in electrically noisy environment applications such as industrial process control or power inverters.

The SN75LBC182 and SN65LBC182 bus pins also exhibit a high input resistance equivalent to one-fourth unit load allowing connection of up to 128 similar devices on the bus. The high ESD tolerance protects the device for cabled connections. (For an even higher level of protection, see the SN65/75LBC184, literature number SLLS236.)

The differential driver design incorporates slew-rate-controlled outputs sufficient to transmit data up to 250 kbps. Slew-rate control allows longer unterminated cable runs and longer stub lengths from the main backbone than possible with uncontrolled voltage transitions. The receiver design provides a fail-safe output of a high level when the inputs are left floating (open circuit). Very low device supply current can be achieved by disabling the driver and the receiver.

The SN65LBC182 is characterized for operation from  $-40^{\circ}$ C to 85°C, and the SN75LBC182 is characterized for operation from 0°C to 70°C.

## functional block diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

<sup>†</sup>The signaling rate of a line, is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



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SN65LBC182D (Marked as 6LB182) SN75LBC182D (Marked as 7LB182)

SN65LBC182P (Marked as 65LBC182) SN75LBC182P (Marked as 75LBC182) (TOP VIEW)

> 8 🗆 V<sub>CC</sub> 7 🗖 В

5 GND

6 🗖 A

1

3

DE 🗖

D 🗖 4

schematic of inputs and outputs Vcc ≶ A Port Only **16 k**Ω **12** μ**A** Nominal **72 k**Ω A or B I/O **16 k**Ω ≶ **B** Port Only **12** μ**Α** Ş Nominal h

#### **Function Tables**

יוסח	VED
υπι	

BRITER											
INPUT	ENABLE DE	OUTI	PUTS								
D	А	В									
Н	Н	Н	L								
L	Н	L	Н								
Х	L	Z	Z								
Open	Н	Н	L								

#### RECEIVER

DIFFERENTIAL INPUTS	ENABLE RE	OUTPUT R
$V_{ID} \ge 0.2 V$	L	Н
$-0.2V < V_{ID} < 0.2 V$	L	?
V <sub>ID</sub> ≤ -0.2 V	L	L
Х	н	Z
Open	L	Н

#### **AVAILABLE OPTIONS**

		PACKAGE
TA	PLASTIC SMALL-OUTLINE <sup>†</sup> (JEDEC MS-012)	PLASTIC DUAL-IN-LINE PACKAGE (JEDEC MS-001)
0°C to 70°C	SN75LBC182D	SN75LBC182P
-40°C to 85°C	SN65LBC182D	SN65LBC182P

<sup>†</sup>Add R suffix for taped and reel.

<sup>†</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



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#### absolute maximum ratings<sup>†</sup> over operating free-air temperature range unless otherwise noted

Supply voltage range, (see Note 1) V <sub>CC</sub> Voltage range at any bus terminal (A or B) Input voltage, V <sub>I</sub> (D, DE, R or RE)	–15 V to 15 V
Receiver output current, IO	
Electrostatic discharge: Human body model (see Note 2)	
<b>č ř</b> ( , , ,	All pins 3 kV
Contact discharge (IEC61000-4-2)	A, B, GND
Air discharge (IEC61000-4-2)	
Continuous total power dissipation	See Dissipation Rating Table

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.

#### **DISSIPATION RATING TABLE** $T_A \le 25^{\circ}C$ T<sub>A</sub> = 70<sup>°</sup>C T<sub>A</sub> = 85<sup>°</sup>C **DERATING FACTOR**<sup>‡</sup> PACKAGE ABOVE $T_A = 25^{\circ}C$ **POWER RATING POWER RATING POWER RATING** 5.8 mW/°C D 725 mW 464 mW 377 mW P 1150 mW 9.2 mW/°C 736 mW 598 mW

<sup>‡</sup> This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow. NOTE: The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature

#### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>		4.75	5	5.25	V
Voltage at any bus I/O terminal (separately or comm	voltage, VIH     D, DE, RE       voltage, VIL     Driver       ottage, VID (see Note 3)     Driver			12	V
High-level input voltage, VIH		2			
Low-level input voltage, VIL	D, DE, RE			0.8	V
Differential input voltage, VID (see Note 3)		-12		12	V
	Driver	-60		60	
Itage at any bus I/O terminal (separately or common gh-level input voltage, V <sub>IH</sub> w-level input voltage, V <sub>IL</sub>	Receiver	-8		4	mA
Operating free air temperature T	SN65LBC182	-40		85	°C
Operating nee-an temperature, 1A	SN75LBC182	0		70	U

NOTE 3: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.



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### driver electrical characteristics over recommended operating conditions

	PARAMETER		TEST COND	ITIONS	MIN	TYP†	MAX	UNIT
VIK	Input clamp voltage		lj = -18 mA	-1.5			V	
VO	Output voltage		IO = 0		0		VCC	V
N/ 1	Differential and a dealer have		RL = 54 Ω,	See Figure 1	1.5	2.2	VCC	V
IVODI	Differential output voltage		$V_{\text{test}} = -7 \text{ V to } 12 \text{ V},$	See Figure 2	1.5	2.2	VCC	V
$\Delta V_{OD}$	Change in magnitude of differentia	al output voltage			-0.2		0.2	
VOC(SS)	Steady-state common-mode outpo	ut voltage	See Figure 1		1		3	V
ΔVOC(SS)	Change in steady-state common-movel voltage	ode output			-0.2		0.2	v
V <sub>OC</sub> (PP)	Peak-to-peak change in common- voltage during state transitions	mode output	See Figures 1 and 4			0.8		V
IOZ	High-impedance output current		See receiver input cur	rents				
IН	High-level input current (D, DE)		V <sub>I</sub> = 2.4 V				50	μA
۱ <sub>IL</sub>	Low-level input current (D, DE)	V <sub>I</sub> = 0.4 V		-50			μA	
IOS	Short-circuit output current		$V_{O} = -7 V$ to 12 V		-250		250	mA
	<b>2 1 1</b>	SN75LBC182				12	25	
ICC	Supply current	SN65LBC182	No load, DE at $V_{CC}$ ,	RE at V <sub>CC</sub>		12	30	mA

<sup>†</sup> All typical values are at  $V_{CC} = 5$  V and  $T_A = 25^{\circ}C$ .

## driver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST C	TEST CONDITIONS			MAX	UNIT
t <sub>r</sub>	Differential output signal rise time			0.25	0.72	1.2	
t <sub>f</sub>	Differential output signal fall time	]	0.25	0.73	1.2		
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output	$R_L = 54 \Omega$ , $C_L = 50 pF$ , See Figure 3				1.3	μs
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	occ rigure o				1.3	
<sup>t</sup> sk(p)	Pulse skew (t <sub>PHL</sub> – t <sub>PLH</sub> )				0.075	0.15	
<sup>t</sup> PZH	Output enable time to high level	D 440.0	0			3.5	_
<sup>t</sup> PHZ	Output disable time from high level	R <sub>L</sub> = 110 Ω,	See Figure 5			3.5	μs
<sup>t</sup> PZL	Output enable time to low level	D 440.0				3.5	_
<sup>t</sup> PLZ	Output disable time from low level	R <sub>L</sub> = 110 Ω,	See Figure 6			3.5	μs



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## receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CON	DITIONS	MIN	TYP†	MAX	UNIT
$V_{IT+}$	Positive-going input threshold voltage					0.2	V
$V_{IT-}$	Negative-going input threshold voltage			-0.2			V
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT+</sub> – V <sub>IT-</sub> )				70		mV
VIK	Enable-input clamp voltage	Ij = -18 mA		-1.5			V
VOH	High-level output voltage	$V_{ID} = 200 \text{ mV}, I_O = -8 \text{ mA},$	See Figure 7	2.8			V
VOL	Low-level output voltage	$V_{ID} = 200 \text{ mV}, I_O = 4 \text{ mA},$	See Figure 7			0.4	V
IOZ	High-impedance-state output current	$V_{O} = 0.4$ to 2.4 V				±1	μA
		$V_{IH} = 12 V, V_{CC} = 5 V$				250	
		V <sub>IH</sub> = 12 V, V <sub>CC</sub> = 0 V				250	
1 <sub>1</sub>	Bus input current	$V_{IH} = -7 V$ , $V_{CC} = 5 V$	Other input at 0 V	-200			μA
		$V_{IH} = -7 V$ , $V_{CC} = 0 V$		-200			
IIН	High-level input current (RE)	VIH = 2 V				50	μA
۱ <sub>IL</sub>	Low-level input current (RE)	V <sub>IL</sub> = 0.8 V		-50			μA
	Current current	Nalaad	DE at 0 V, RE at 0 V			3.5	mA
ICC	Supply current	No load	DE at 0 V, RE at V <sub>CC</sub>		175	250	μA

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

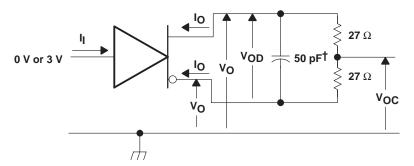
# receiver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tr	Differential output signal rise time			20		
t <sub>f</sub>	Differential output signal fall time			20		
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output	$C_{L} = 50 \text{ pF},$ See Figure 7			150	ns
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	1			150	
<sup>t</sup> PZH	Output enable time to high level				100	
<sup>t</sup> PZL	Output enable time to low level	Soo Figuro 8			100	ns
<sup>t</sup> PHZ	Output disable time from high level	See Figure 8			100	
<sup>t</sup> PLZ	Output disable time from low level	1			100	ns
<sup>t</sup> sk(p)	Pulse skew  t <sub>PHL</sub> – t <sub>PLH</sub>				50	ns



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#### PARAMETER MEASUREMENT INFORMATION



<sup>&</sup>lt;sup>†</sup>Includes probe and jig capacitance

#### Figure 1. Driver Test Circuit, V<sub>OD</sub> and V<sub>OC</sub> Without Common-Mode Loading

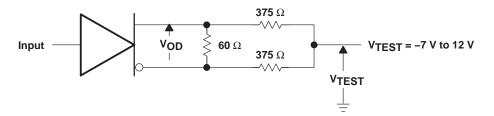
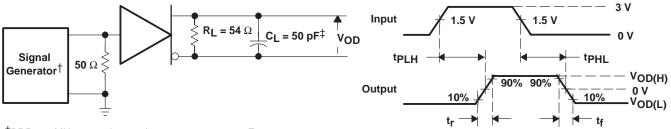


Figure 2. Driver Test Circuit, V<sub>OD</sub> With Common-Mode Loading



 $^{\dagger}\text{PRR}$  = 1 MHz, 50% duty cycle,  $t_{f}$  < 6 ns,  $t_{f}$  < 6 ns,  $Z_{O}$  = 50  $\Omega$   $^{\ddagger}\text{Includes}$  probe and jig capacitance



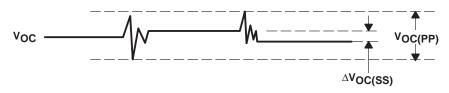
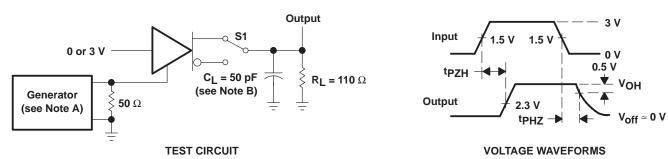


Figure 4. V<sub>OC</sub> Definitions



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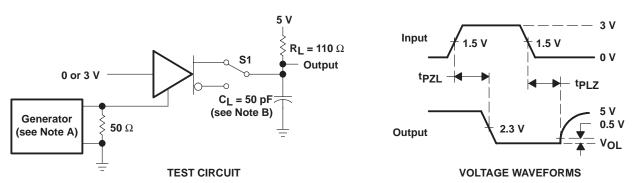
### PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, t<sub>r</sub>  $\leq$  10 ns, t<sub>f</sub>  $\leq$  10 ns, Z<sub>O</sub> = 50  $\Omega$ .

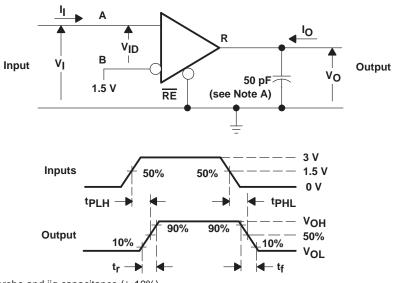
B. CL includes probe and jig capacitance.

#### Figure 5. Driver tPZH and tPHZ Test Circuit and Voltage Waveforms



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, t<sub>r</sub>  $\leq$  10 ns, t<sub>f</sub>  $\leq$  10 ns, Z<sub>O</sub> = 50  $\Omega$ .
  - B. CL includes probe and jig capacitance.

#### Figure 6. Driver tpzL and tpLZ Test Circuit and Voltage Waveforms

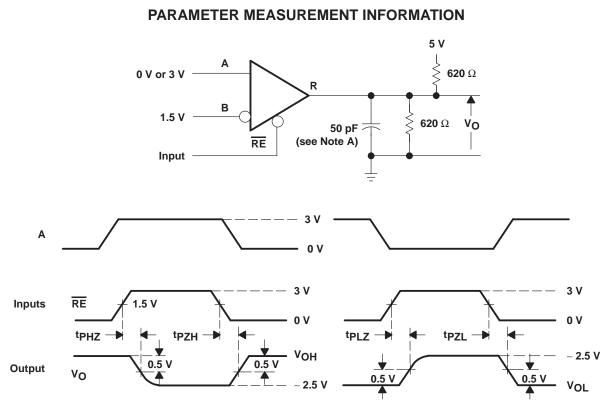


NOTE A: This value includes probe and jig capacitance (± 10%).

#### Figure 7. Receiver tPLH and tPHL Test Circuit and Voltage Waveforms



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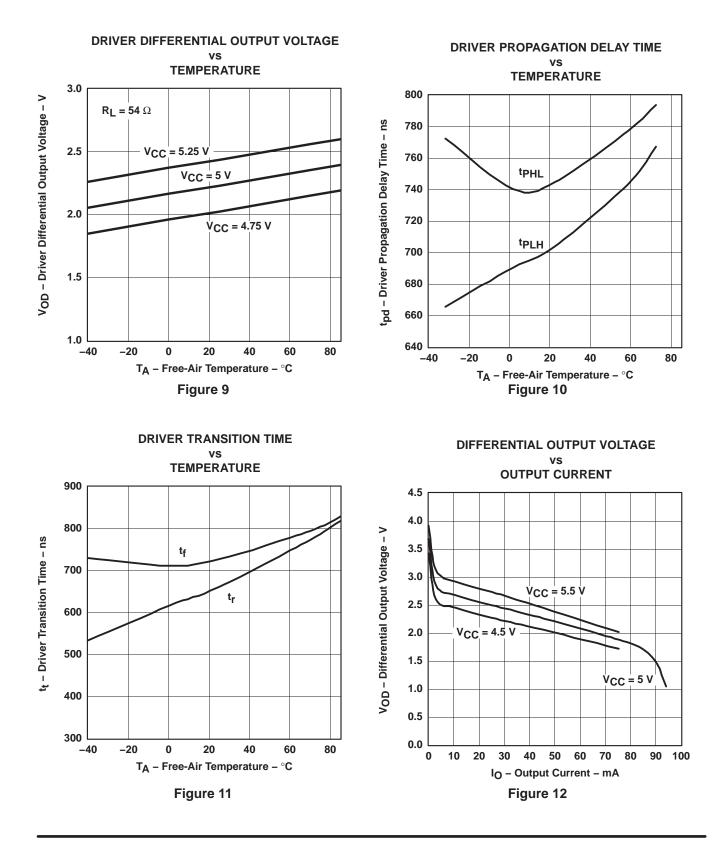
NOTE A: This value includes probe and jig capacitance ( $\pm$  10%).

Figure 8. Receiver  $t_{PZL}$ ,  $t_{PLZ}$ ,  $t_{PZH}$ , and  $t_{PHZ}$  Test Circuit and Voltage Waveforms



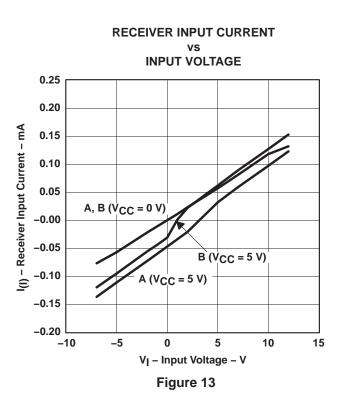
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## TYPICAL CHARACTERISTICS



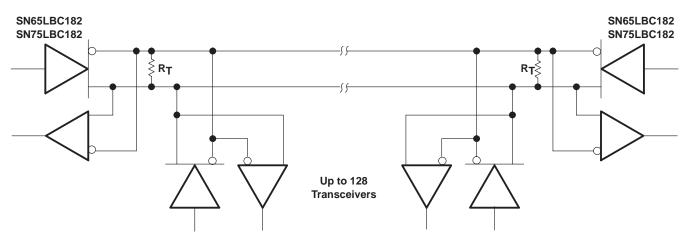


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#### **TYPICAL CHARACTERISTICS**





NOTE A: The line should be terminated at both ends in its characteristic impedance (R<sub>T</sub> = Z<sub>O</sub>). Stub lengths off the main line should be kept as short as possible.

Figure 14. Typical Application Circuit



#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65LBC182D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC182DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC182DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC182DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC182P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65LBC182PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC182D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC182DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC182DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC182DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC182P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC182PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## PACKAGE OPTION ADDENDUM



In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



## PACKAGE MATERIALS INFORMATION

19-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC182DR	SOIC	D	8	2500	340.5	338.1	20.6
SN65LBC182DR	SOIC	D	8	2500	346.0	346.0	29.0
SN75LBC182DR	SOIC	D	8	2500	340.5	338.1	20.6
SN75LBC182DR	SOIC	D	8	2500	346.0	346.0	29.0

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AA.



## **MECHANICAL DATA**

MPDI001A - JANUARY 1995 - REVISED JUNE 1999



- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg\_info.htm



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